

# Single Supply, Low Power Precision Op Amp

**AD821** 

# **FEATURES**

True Single Supply Operation:
Input and Output Voltage Ranges
Include Ground
Output Voltage Swing to 50mV of Each Rail
Low Power: 400µA Supply Current max
250µV Input Offset Voltage
1.3MHz Gain Bandwidth Product
3V/µs Slew Rate
Single and Dual Supply Capability

#### **APPLICATIONS**

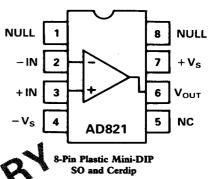
Battery Powered Precision Instrumentation
Strain Gage Signal Conditioners
Instrumentation Amplifiers
Thermocouple Amplifiers
Multiple Limit Threshold Detection
12- to 14-Bit Data Acquisition Systems
Available in 8-Pin Plastic Mini-DIP, SOIC and
Hermetic Cerdip Packages
Dual Version – AD822, Quad Version – AD824
Available

#### PRODUCT DESCRIPTION

The AD821 is a precision, low of the FLT input it modifies of amp that can operate from a single supply of  $(4.75 \pm t) + 36V$  or dual supplies of  $\pm 2.4V$  to  $\pm 16V$ . It has true single supcapability with its input voltage range including the negative rail, allowing the AD821 to accommodate input signals down or ground in the single supply mode. Its output voltage swing extends to within 50mV of each rail providing the maximum possible output dynamic range to the user.

Low input offset voltage (250 $\mu$ V max), low offset voltage drift (3 $\mu$ V/°C max), low input bias current (<10 $\mu$ A) and low supply currents (400 $\mu$ A) max) mark the AD821 with true dc precision at low power operating conditions. Combined with unity gain bandwidth of 1.3MHz and 3V/ $\mu$ s slew rate, the AD821 offers the best combination of ac and dc specs to the single supply op amp user. Performance in 12- to 14-bit applications is ensured with the AD821's low noise 26nV/ $\mu$ Mz), high open-loop gain (10 $\mu$ V/mV) and 4 $\mu$ s settling to 0.01%.

### AD821 FUNCTIONAL BLOCK DIAGRAM



The AD-321 is an excellent choice for battery powered precision trumeptation applications – wherein the extended input and output ral go at ord the AD821 its versatility in these application.

A p. 321 is available in five performance grades. The AD821J and AD821K are rated over the commercial temperature range of 0 to \$100. The AD821A and AD821B are rated over the fit stril temperature range of \$-40^{\circ}\$C to \$+85^{\circ}\$C. The AD821S is raily dover the military temperature range of \$-55^{\circ}\$C to \$+125^{\circ}\$C and is available processed to MIL-STD-883B, Rev. C.

Extended reliability PLUS screening is available, specified over the commercial and industrial temperature range. PLUS screening includes a 168 hour burn-in, as well as other environmental and physical tests.

## PRODUCT HIGHLIGHTS

- 1. True single supply operation input voltage range includes the negative rail.
- 2. Output voltage range extends to 50mV of each rail.
- 3. Low power, low supply current.
- Common-mode rejection of 90dB and open-loop gain of 10<sup>7</sup>V/mV ensure 12- to 14-bit accuracy in high-speed data acquisition circuits.
- 5. Dual version AD822, quad version AD824 also available.

SPECIFICATIONS (@ + 25°C unless otherwise noted)

Model		AD821J/A/S			AD821B/K			
	Conditions <sup>1</sup>	Min	Тур	Max	Min	Тур_	Max	Units
NPUT CHARACTERISTICS					l			
Input Offset Voltage <sup>2</sup>	$V_{CM} = 0$	1			]			
••••••••••••••••••••••••••••••••••••••	Condition 1, $V_O = 0V$	l	0.3	1*		0.1	0.25*	mV
	Condition 2, $V_O = 1.4V$	i	0.3	i*	l .	0.1	0.25*	mV
		l	0.5	1.5/1.6/2*	l	0	0.4*	mV
	T <sub>min</sub> to T <sub>max</sub>	1		1.3/1.6/2"	İ		3*	μV/°C
Input Offset Voltage Drift		1						
Input Bias Current <sup>3</sup>		1	15	30		10	20	pA
	T <sub>min</sub> to T <sub>max</sub>	l		0.68/2/30			0.5/1.3	nA
Input Offset Current		1	5	15		3	7	pΑ
	T <sub>min</sub> to T <sub>max</sub>			0.34/0.96/15			0.16/0.45	nA
Input Resistance	Differential		5 × 10			5 × 10		Ω
Input Capacitance	Dimerena.	1	3			3		pF
Common-Mode Voltage Range	Condition 1	-Vs	-	$+ V_{S} - 1$	$-v_s$	•	$+ V_S - 1$	v
								lù
	Condition 2	$-\mathbf{v_s}$		$+ V_S - 1$	-V <sub>s</sub>	,	$+V_S-1$	v
Differential Voltge Range <sup>4</sup>	Condition I	$-\mathbf{V}_{\mathbf{S}}$		$+ V_S + 0.6$	$-\mathbf{V}_{S}-0.6$		$+ V_S + 0.6$	
	Condition 2	$-\mathbf{V_{S}}-\mathbf{V_{S}}$	0.6	$+ V_S + 0.6$	$-V_S-0.6$	6	$+ V_S + 0.6$	V
Common-Mode Rejection	Condition 1	80*			90*			dB
	$V_{CM} = \pm 12V, V_{O} = 0V$				i			l
	Condition 2	80*			90*			dB
		1 50			1 ~			1
	$V_{CM} = 0 \text{ to } 2.5 \text{V}, V_{CO} = 1.4 \text{V}$	00+			00+			dB
Power Supply Rejection Ratio	Condition 1	80*			90*			
	Condition 2	80*			90*			dB
	$4.5 < + V_S < 5.5, V_O = 1.4V$	1			al .			l
Input Noise Voltage	f = 10Hz	1	90	ایر		90		nV/√Hz
input Noise voltage	f = 100Hz	1	90			90		nV/√Hz
	f = 1kHz	l	50		•	50		nV/√Hz
		1	22 4		<b>T</b>	33		nV/√Hz
	f = 10kHz	l .	33	A 18 2				
	f = 100kHz		21		ı	21		nV/√Hz
Input Noise Current	f = 1kHz	1		<b>4</b>	I	0.01		pA/√Hz
· · · · · · · · · · · · · · · · · · ·		4	1 1 W	<u> </u>				
OUTPUT CHARACTERISTICS		- E.P		_ 17				
Output Voltage Swing	Condition 1, Condition 2	40 11	<b>A</b>		٦			
	2k\O Load	T Di	max from	ach Rail		max from		
	10kΩ Load 🔒 🔌	100r	nV mas (rous)	h ail	100mV	/ max from	Each Rail	į.
	Condition 2	<b>*</b>	45 F W					iv
	ImA Sink	1	T es	Fronti	100mV	max from	Ground	
Short-Circuit Current	Source of Si		<b>1 1 1 1 1 1 1 1 1 1</b>			30		mA
Short-Circuit Current	3000 000	- K	<b>D</b> 30		<b></b>			1071
GAIN		4 4	_ ~ ~ ~	Y E.	i			
Open Loop	Condition 1		TO.	<b>B</b> -	1			
Open Loop	V <sub>O</sub> = ± 14V			•	1			
	2k() Load	50	000		500	1,000		V/mV
		1.00	10,000		1,000	10,000	-	V/mV
	10kΩ Load	1,000	10,000		1,000	10,000		V/111 V
	Condition 2	1			1			I
	$V_{\rm O} = 0.5 \text{V} \text{ to } 4.5 \text{V}$	1			I			I
	2kí) Load	500	1,000		500	1,000		V/mV
	10kΩ Load	1,000	10,000		1,000	10,000		V/mV
		1 .,	-,		<del>1                                    </del>			<del>                                     </del>
DYNAMICCHARACTERISTICS	!	1			1			1
Gain Bandwidth Product	1	1	1.3		I	1.3		MHz
Rated Performance	1	1			1			I
Full Power Bandwidth	i	1	48		1	48		kHz
	l	l	3		1	3		V/µs
Slew Rate	103/50.10/	1	4		1	4		μs
Settling Time	10V Step to 0.1%	L	4			7		μ.,
POWER SUPPLY							-	
Operating Voltage Range	Differential	+ 4*		+ 36*	+ 4*		+ 36*	v
	I	1 '		400*	1		400*	μА
Quiescent Current	<u> </u>	ļ		700	<b></b>			ļ
TEMPERATURE RANGE					1	-		
Rated Performance	E	1			1			1
Commercial (0 to +70°C)	1		AD821JN, Al	08211R	1	AD821KN	1	
	1		AD821A		1	AD821BC		
Industrial (-25°C to +85°C)	1	1			1	"POZIBC	4	1
Military ( $-55^{\circ}$ C to $+125^{\circ}$ C)	1		AD8218	Ų	1			
PACKAGE OPTIONS5	1				1			
	I	1	AD8211	N	1	AD821KN	J	1
Plastic (N-8)	I	1			i			· ·
Cerdip (Q-8)	Ī	1 4	AD821AQ, A		1	AD821BC	Ł	1
SOIC (R-8)			AD821]					

# 2-154 OPERATIONAL AMPLIFIERS

NOTES \*Indicates parameter guaranteed and tested. \*Condition 1:  $\pm$  15V power supply. \*Condition 1:  $\pm$  15V power supply. \*Condition 2:  $\pm$  5V power supply. \*Input offset voltage specifications are guaranteed after 5minutes of operation at  $T_A = 25^{\circ}C$ . \*Plais Current specifications are guaranteed maximum at either input after 5minutes of operation at  $T_A = \pm$  25°C. \*Conditional temperature: the current doubles every 10°C.

For higher temperature, the current doubles every 10°C.

<sup>&</sup>lt;sup>4</sup>Defined as voltage between inputs. <sup>5</sup>See Section 16 for package outline information.

Specifications subject to change without notice.

ABSOLUTE MAXIMUM RATINGS
Supply Voltage
Output Short-Circuit Duration Indefinite
Internal Power Dissipation
Plastic
Cerdip
SOIC
Storage Temperature Range65°C to +150°C
Operating Temperature Range
AD821J/R 0 to +70°C
AD821A/B
AD821S55°C + 125°C
Maximum Junction Temperature
Lead Temperature Range (Soldering 10sec + 260°C
Lead Temperature Range (Soldering Tosed
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